	Type	Hits	Search Text	DBs
1	IS&R	5	(("6017823") or ("6498067") or ("20030011080") or ("20030027414") or ("20040005750")).PN.	US-PGPUB; USPAT
2	BRS	7795	(CMOS or MOSFET) and gate and spacer and silicide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
3	BRS	3677	S2 and (spacer with (etching or removing))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
4	BRS	267	S3 and (spacer with height)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB

	Type	Hits	Search Text	DBs
5	BRS	3361	(CMOS or MOSFET) and gate and (spacer with etching) and silicide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
6	BRS	26	S5 and spacer adj height	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
7	BRS	83	S2 and (spacer with (etching or removing)) and work$function	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
8	BRS	2038	438/630,645,651,655,663,664,6 82.ccls.	US-PGPUB; USPAT
9	BRS	381	S8 and gate and (spacer with etching)	US-PGPUB; USPAT
10	BRS	361	S8 and (silicide with thickness) and (CMOS or MOSFET)	US-PGPUB; USPAT

	Type	Hits	Search Text	DBs
11	BRS	217	438/630.ccls.	US-PGPUB; USPAT
12	BRS	3478	silicide near3 thickness	US-PGPUB; USPAT
13	BRS	2547	silicide near2 thickness	US-PGPUB; USPAT
14	BRS	1140	silicide near thickness	US-PGPUB; USPAT
15	BRS	997	S14 and gate	US-PGPUB; USPAT
16	BRS	8	("6103610").URPN.	USPAT
17	BRS	4	("4877755" | "5034348" | "5736461" | "6040606").PN.	US-PGPUB; USPAT; USOCR
18	IS&R	1	("6344388").PN.	USPAT
19	BRS	1265	438/592.ccls.	US-PGPUB; USPAT
20	BRS	501	S19 and gate and (silicide with (thick$4 or height))	US-PGPUB; USPAT
21	BRS	242	S20 and ((remov$4 or etch$3) with spacer)	US-PGPUB; USPAT

9/9/05, EAST Version: 2.0.1.4

	Type	Hits	Search Text	DBs
22	BRS	7	("5034348" | "5610088" | "5654212" | "5953612" | "6040606" | "6103610" | "6235568").PN.	US-PGPUB; USPAT; USOCR

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	135	(gate and spacer and (remov$3 or etch$3) and (silicide with electrode) and (height or thick$4)).CLM.	US-PGPUB	OR	ON	2005/09/09 12:40